Diode Module

Features

- A package of series of two diodes
- With high thermal conductivity DBC as the Insulation
- Welding by vacuum welding technology, which provide high reliability

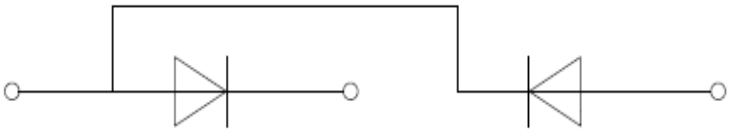
Product Summary

Parameter	Value	Unit
V_{RRM}	2000	V
$I_{F(AV)}$(@ T_C = 100)	380	A
I_{FSM}(@ t_P = 10ms)	12000	A
V_F(Max)	1.60	V

Applications

- AC converter
- Inverter
- DC motor





Absolute Maximum Ratings (@ T_C

Non-repetitive peak reverse voltage	Tvj = 25°C	V_{RSM}	2100	V
Average forward current	T_C = 100°C	$I_{F(AV)}$	380	A
Forward surge current	1/2 cycle, Sine wave, 50Hz Tvj = 25	I_{FSM}	12000	A
I^2t value for fusing		I^2t	720000	A^2s
RMS isolation voltage	A.C 50Hz(1s/1min)	V_{ISO}	3600/3000	V
Junction temperature range		T_J	-40 ~ +150	
Storage temperature range		T_{stg}	-40 ~ +125	

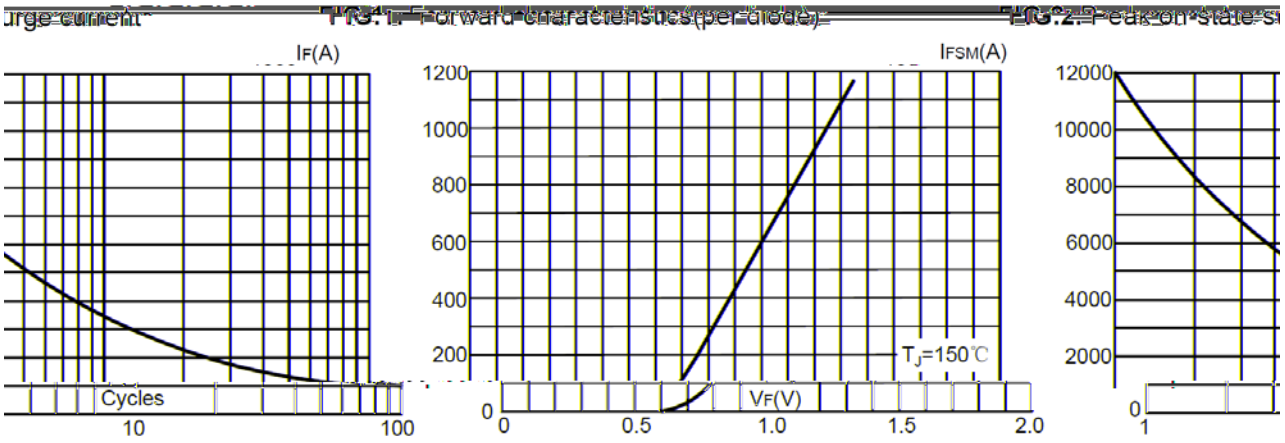
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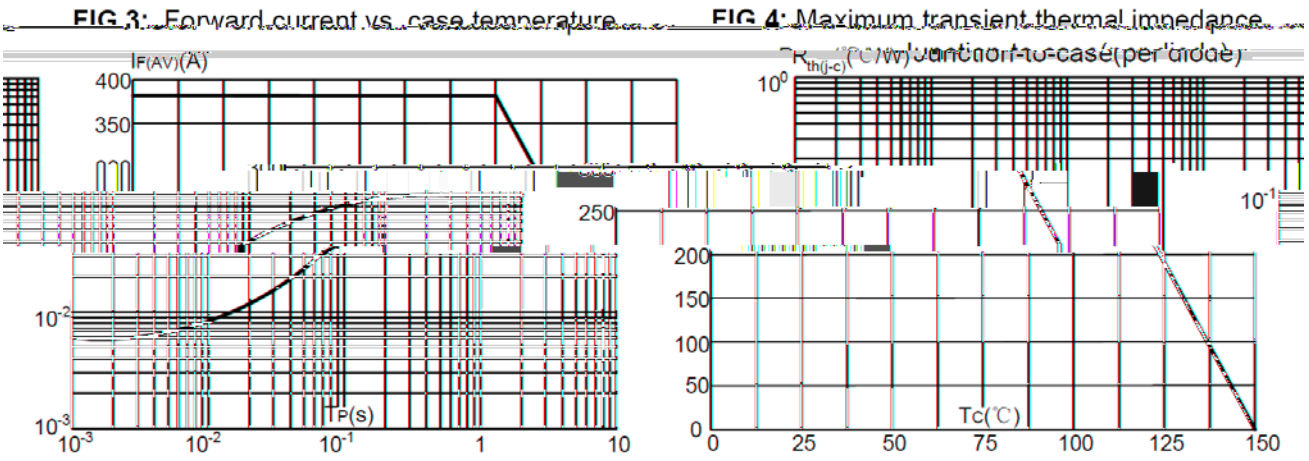
Electrical Characteristics (@ T_C = 25°C unless otherwise specified)

Parameter	Conditions	Symbol	Values	Unit

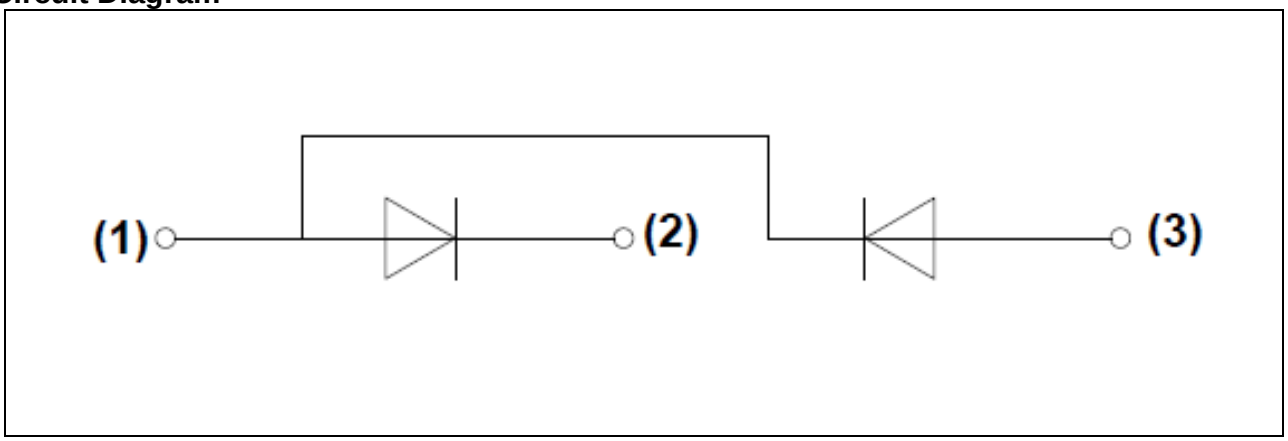
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Typical Electrical & Thermal Characteristics



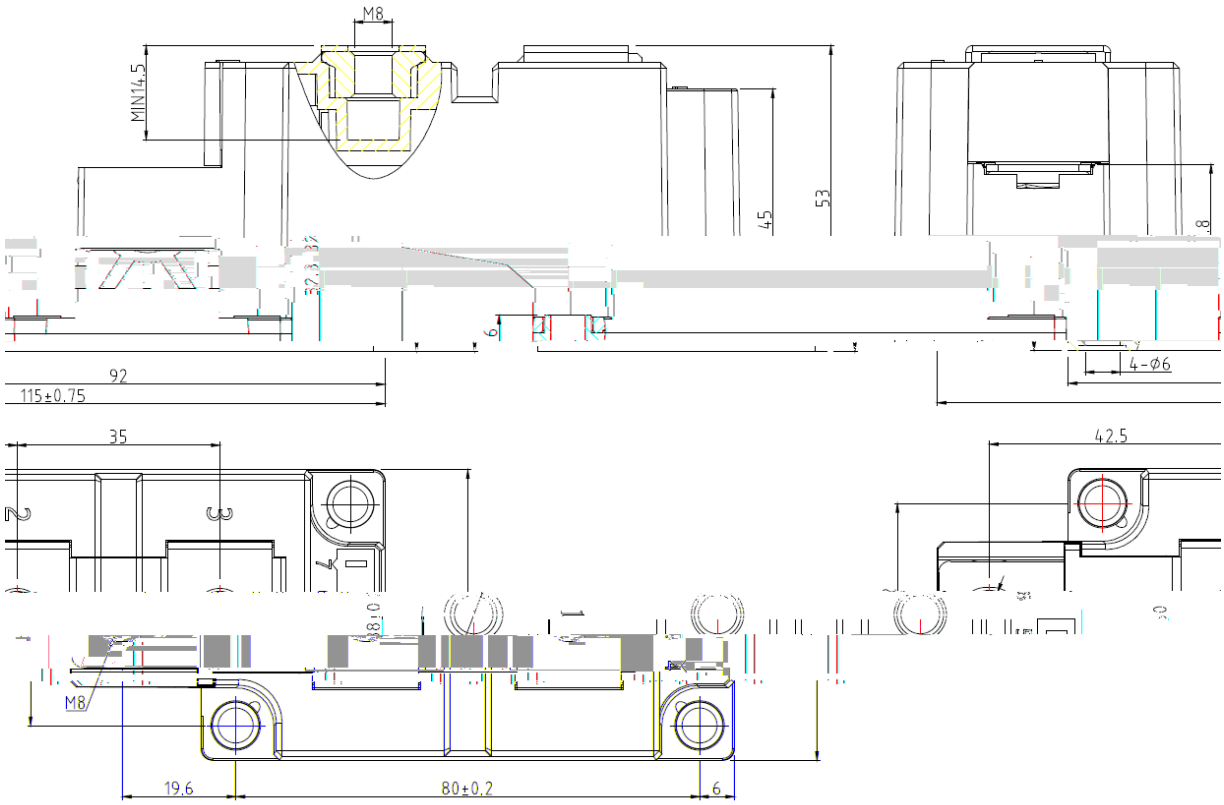


Circuit Diagram



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Package Outlines (mm)



Unit of measurement: mm

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